

# 2N5550, 2N5551

Preferred Device

## Amplifier Transistors

### NPN Silicon

#### Features

- Pb-Free Packages are Available\*
- Device Marking: Device Type, e.g., 2N5550, Date Code

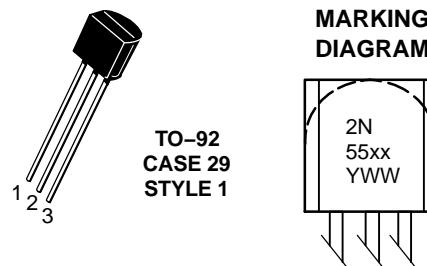
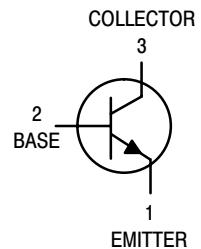
#### MAXIMUM RATINGS

Rating	Symbol	2N5550	2N5551	Unit
Collector – Emitter Voltage	$V_{CEO}$	140	160	Vdc
Collector – Base Voltage	$V_{CBO}$	160	180	Vdc
Emitter – Base Voltage	$V_{EBO}$	6.0		Vdc
Collector Current – Continuous	$I_C$	600		mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	625 5.0		mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	1.5 12		W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-55 to +150		$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	$^\circ\text{C/W}$



55xx      Specific Device Code  
Y           = Year  
WW          = Work Week

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

# 2N5550

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector-Emitter Breakdown Voltage (Note 1) ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $I_B = 0$ )	$V_{(\text{BR})\text{CEO}}$ 2N5550 2N5551	140 160	— —	Vdc
Collector-Base Breakdown Voltage ( $I_C = 100 \mu\text{A}_\text{dc}$ , $I_E = 0$ )	$V_{(\text{BR})\text{CBO}}$ 2N5550 2N5551	160 180	— —	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \mu\text{A}_\text{dc}$ , $I_C = 0$ )	$V_{(\text{BR})\text{EBO}}$	6.0	—	Vdc
Collector Cutoff Current ( $V_{CB} = 100 \text{ Vdc}$ , $I_E = 0$ ) ( $V_{CB} = 120 \text{ Vdc}$ , $I_E = 0$ ) ( $V_{CB} = 100 \text{ Vdc}$ , $I_E = 0$ , $T_A = 100^\circ\text{C}$ ) ( $V_{CB} = 120 \text{ Vdc}$ , $I_E = 0$ , $T_A = 100^\circ\text{C}$ )	$I_{\text{CBO}}$ 2N5550 2N5551 2N5550 2N5551	— — — —	100 50 100 50	nAdc $\mu\text{Adc}$
Emitter Cutoff Current ( $V_{EB} = 4.0 \text{ Vdc}$ , $I_C = 0$ )	$I_{\text{EBO}}$	—	50	nAdc

**ON CHARACTERISTICS** (Note 1)

DC Current Gain ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )  ( $I_C = 10 \text{ mA}_\text{dc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )  ( $I_C = 50 \text{ mA}_\text{dc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )	$h_{FE}$ 2N5550 2N5551  2N5550 2N5551  2N5550 2N5551	60 80  60 80  20 30	— —  250 250  — —	— —  — —  — —
Collector-Emitter Saturation Voltage ( $I_C = 10 \text{ mA}_\text{dc}$ , $I_B = 1.0 \text{ mA}_\text{dc}$ )  ( $I_C = 50 \text{ mA}_\text{dc}$ , $I_B = 5.0 \text{ mA}_\text{dc}$ )	$V_{CE(\text{sat})}$ Both Types  2N5550 2N5551	— —  — —	0.15 0.25 0.20	Vdc
Base-Emitter Saturation Voltage ( $I_C = 10 \text{ mA}_\text{dc}$ , $I_B = 1.0 \text{ mA}_\text{dc}$ )  ( $I_C = 50 \text{ mA}_\text{dc}$ , $I_B = 5.0 \text{ mA}_\text{dc}$ )	$V_{BE(\text{sat})}$ Both Types  2N5550 2N5551	— —  — —	1.0 1.2 1.0	Vdc

## SMALL-SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product ( $I_C = 10 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 100 \text{ MHz}$ )	$f_T$	100	300	MHz
Output Capacitance ( $V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{\text{obo}}$	—	6.0	pF
Input Capacitance ( $V_{EB} = 0.5 \text{ Vdc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{\text{ibo}}$ 2N5550 2N5551	— —	30 20	pF
Small-Signal Current Gain ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{fe}$	50	200	—
Noise Figure ( $I_C = 250 \mu\text{A}_\text{dc}$ , $V_{CE} = 5.0 \text{ Vdc}$ , $R_S = 1.0 \text{ k}\Omega$ , $f = 1.0 \text{ kHz}$ )	NF	— —	10 8.0	dB

1. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

# 2N5550

## ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
2N5550	TO-92	5,000 Unit / Bulk
2N5550RLRA	TO-92	2,000 Tape & Reel
2N5550RLRP	TO-92	2,000 Tape & Ammo Box
2N5550RLRPG	TO-92 (Pb-Free)	2,000 Tape & Ammo Box
2N5551	TO-92	5,000 Unit / Bulk
2N5551G	TO-92 (Pb-Free)	5,000 Unit / Bulk
2N5551RL1	TO-92	2,000 Tape & Reel
2N5551RLRA	TO-92	2,000 Tape & Reel
2N5551RLRM	TO-92	2,000 Tape & Ammo Box
2N5551RLRP	TO-92	2,000 Tape & Ammo Box
2N5551ZL1	TO-92	2,000 Tape & Ammo Box

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

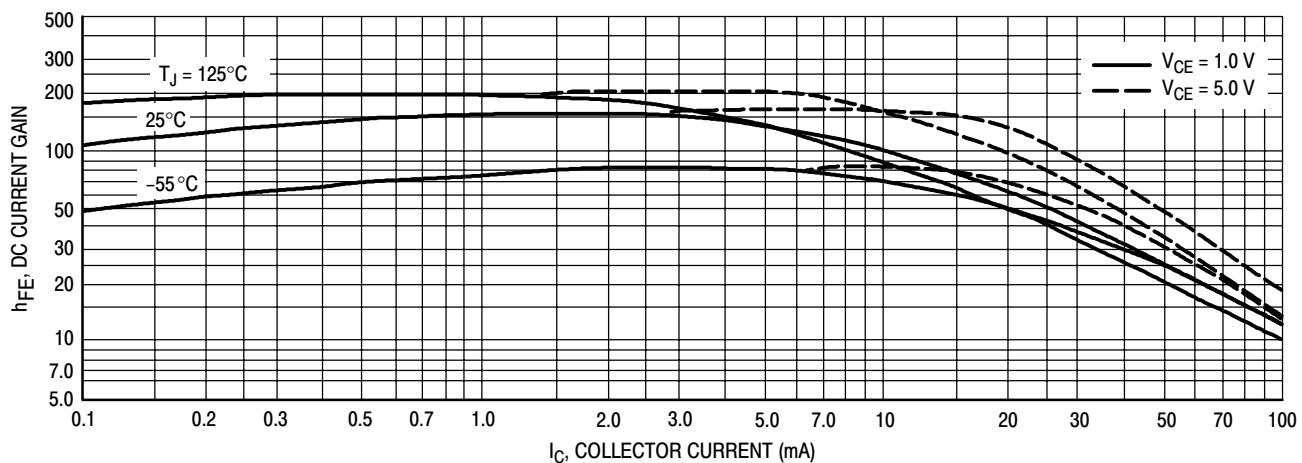
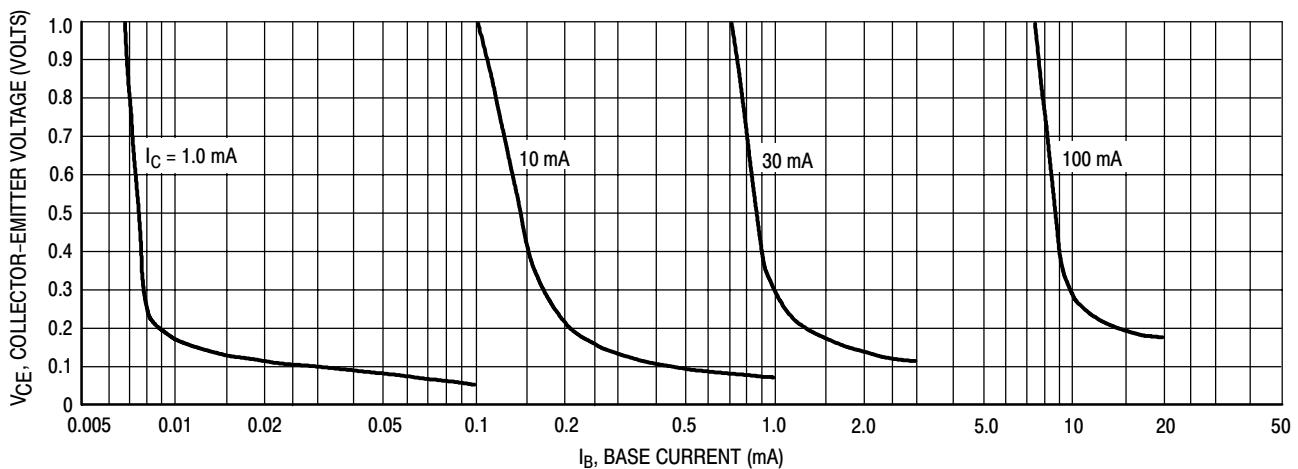
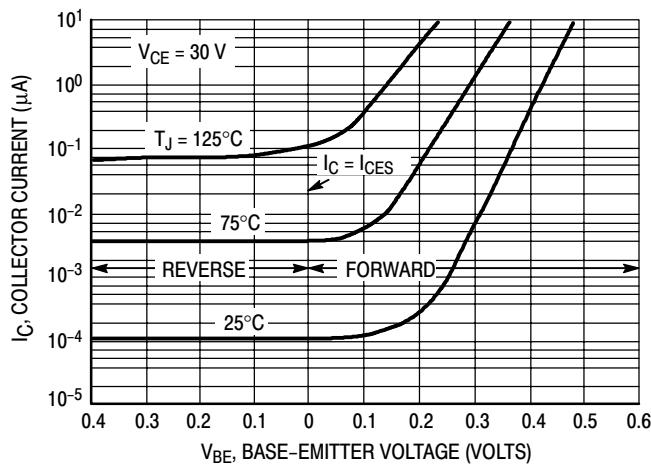


Figure 1. DC Current Gain

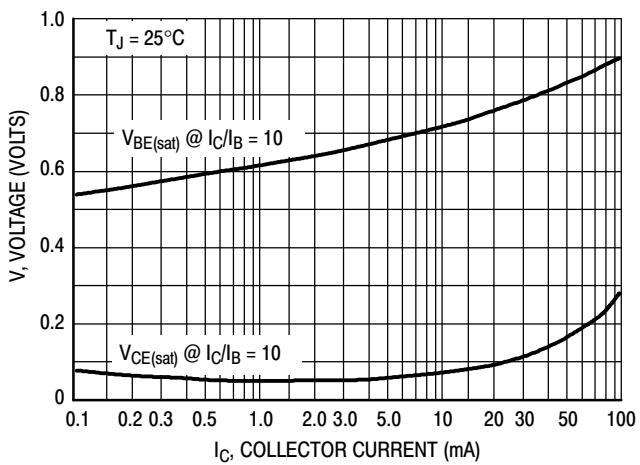
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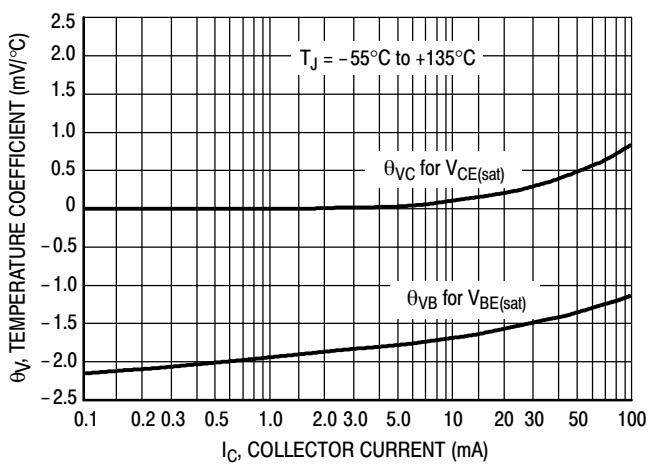
**Figure 2. Collector Saturation Region**



**Figure 3. Collector Cut-Off Region**

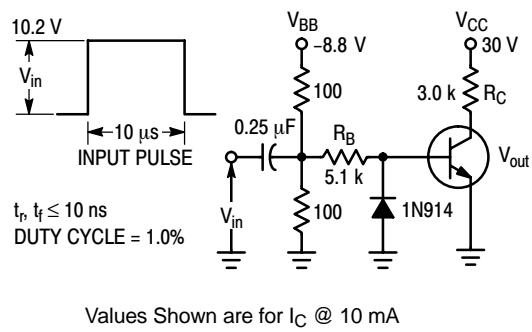


**Figure 4. "On" Voltages**

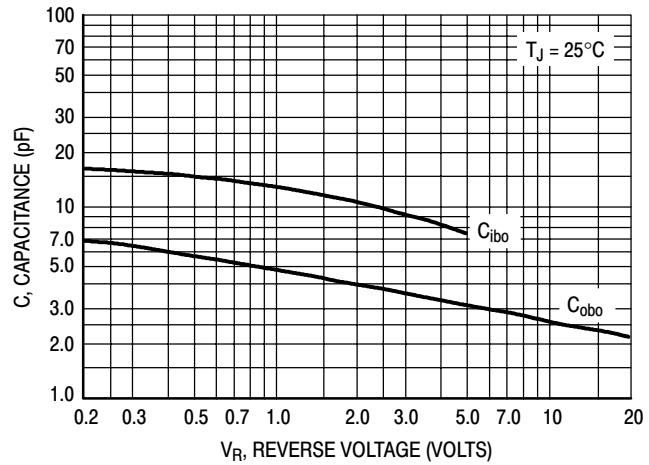


**Figure 5. Temperature Coefficients**

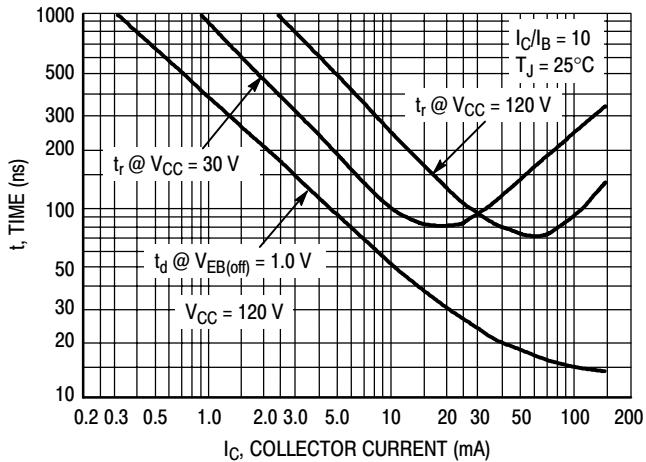
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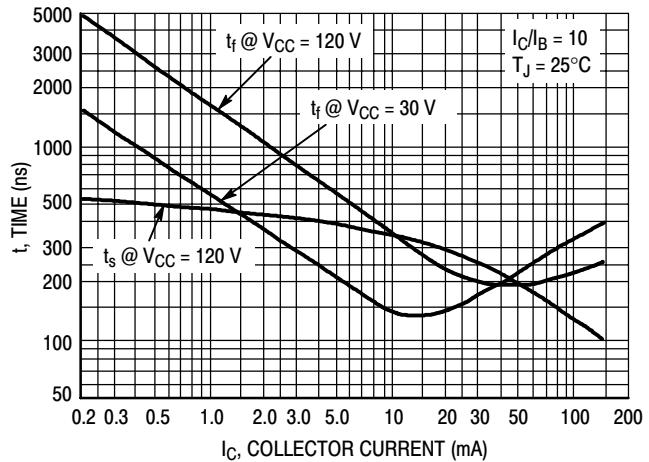
**Figure 6. Switching Time Test Circuit**



**Figure 7. Capacitances**



**Figure 8. Turn-On Time**

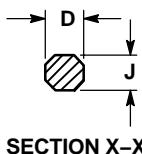
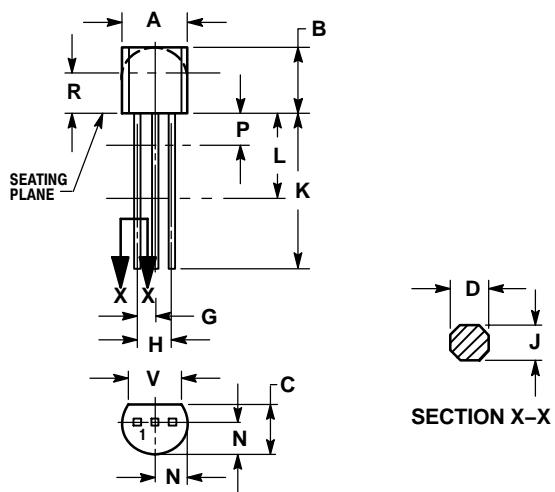


**Figure 9. Turn-Off Time**

# 2N550

## PACKAGE DIMENSIONS

TO-92  
TO-226AA  
CASE 29-11  
ISSUE AL



NOTES:  
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
2. CONTROLLING DIMENSION: INCH.  
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.  
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

STYLE 1:  
PIN 1. Emitter  
2. Base  
3. Collector